imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



LAPT 2SA1186

Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC2837)

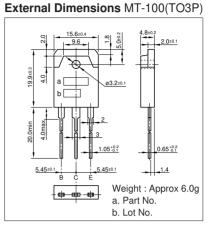
I

Application : Audio and General Purpose

Absolute maximum ratings (Ta=25°C) Symbol Unit Ratings -150 Vсво V VCEO -150 ٧ VEBO -5 V Ic -10 А lв -2 А Pc 100(Ta=25°C) W Tj 150 °C Tstg –55 to +150 °C

Electrical Cl	naracteristics	(Ta=25°C)					
Symbol	Conditions	Ratings	Unit				
Ісво	Vcb=-150V	-100max	μA				
Іево	Veb=-5V	-100max	μΑ				
V(BR)CEO	Ic=-25mA -150min		V				
hfe	VCE=-4V, IC=-3A	50min*					
VCE(sat)	Ic=-5A, IB=-0.5A	-2.0max	V				
fτ	VCE=-12V, IE=1A	-12V, IE=1A 60typ					
Сов	Vcb=-80V, f=1MHz	110typ	pF				
where Depter 0(E0to 100) D(20to 140) V(00to 100)							

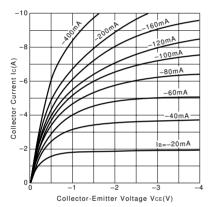
*hFE Rank 0(50 to 100), P(70 to 140), Y(90 to 180)



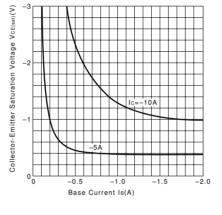
Typical Switching Characteristics (Common Emitter)

Vcc	RL	Ic	VB2	Iв1	I _{B2}	ton	tstg	tf
(V)	(Ω)	(A)	(V)	(mA)	(mA)	(μs)	(μs)	(µs)
-60	12	-5	5	-500	500	0.25typ	0.8typ	0.2typ

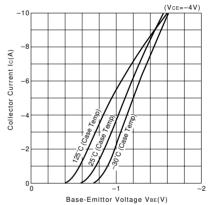
Ic-VcE Characteristics (Typical)

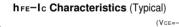


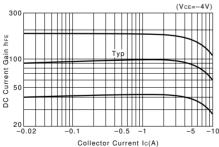
VcE(sat)-IB Characteristics (Typical)



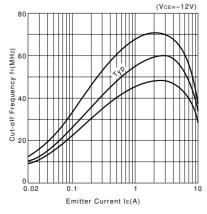
Ic-VBE Temperature Characteristics (Typical)



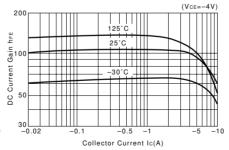




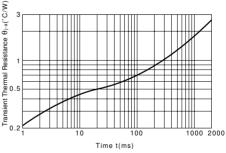
ft-le Characteristics (Typical)



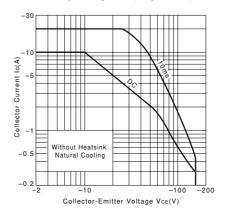
hFE-Ic Temperature Characteristics (Typical)



θ_{j-a} -t Characteristics



Safe Operating Area (Single Pulse)



Pc-Ta Derating

